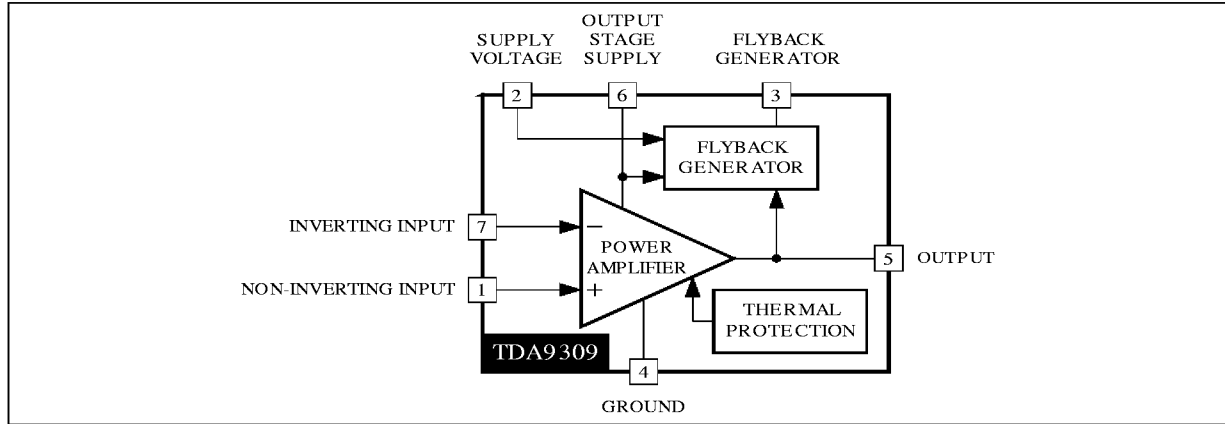


TDA9309

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_S	Supply Voltage (Pin 2) (see note 1)	40	V
V_6	Flyback Peak Voltage (Pin 6) (see note 1)	70	V
V_1, V_7	Amplifier Input Voltage (Pins 1-7) (see note 1)	V_S	V
V_3	Voltage at Pin 3 (see note 5)	$V_S + 3.0$	V
I_O	Maximum Output Peak Current (see notes 2 and 3)	1.5	A
I_s	Maximum Sink Current (first part of flyback) ($t < 1ms$)	1.5	A
I_s	Maximum Source Current ($t < 1ms$) (see note 2)	1.5	A
V_{ESD}	Electrostatic Handling for all pins (see note 4)	2000/300	V
T_{oper}	Operating Ambient Temperature	- 20, + 75	°C
T_{stg}	Storage Temperature	- 40, + 150	°C
T_j	Junction Temperature	+150	°C

- Notes :**
1. Versus Pin 4.
 2. The output current can reach 4A peak for $t \leq 10\mu s$ (up to 200Hz).
 3. Provided SOAR is respected (see Figures 1 and 2).
 4. Equivalent to discharging a 100pF capacitor through a 1.5k Ω serial resistor / 200pF capacitor through 0 Ω resistor.
 5. This will occur during 1st half of flyback pulse.

THERMAL DATA

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction-case Thermal Resistance	Max. 3	°C/W
T_t	Temperature for Thermal Shutdown	150	°C
T_{jr}	Recommended Max. Junction Temperature	120	°C

ELECTRICAL CHARACTERISTICS

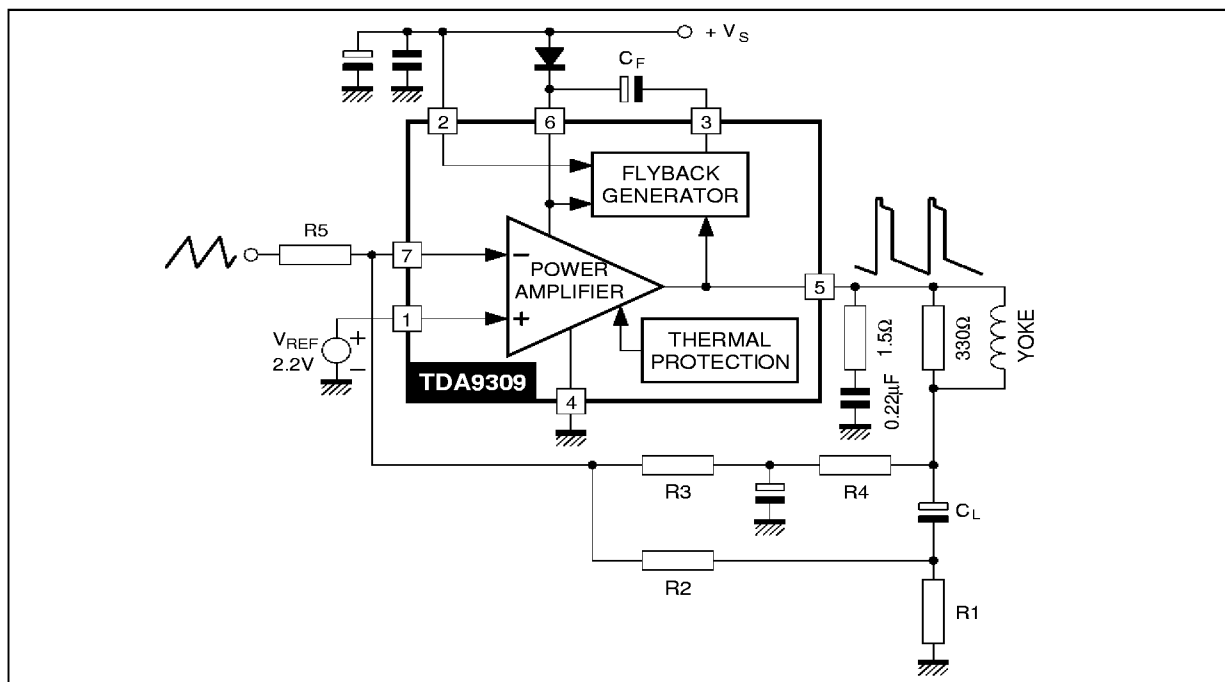
($V_S = 35V$, $T_A = 25^\circ C$, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_S	Operating Supply Voltage Range		10		35	V
I_2	Pin 2 Quiescent Current	$I_3 = 0, I_5 = 0$		9	20	mA
I_6	Pin 6 Quiescent Current	$I_3 = 0, I_5 = 0, V_6 = 35V$	8	19	35	mA
I_O	Max. Peak Output Current				± 1	A
I_1	Amplifier Bias Current	$V_1 = 1V, V_7 = 2.2V$		- 0.6	- 1.5	μA
I_7	Amplifier Bias Current	$V_1 = 2.2V, V_7 = 1V$		- 0.6	- 1.5	μA
V_{IO}	Offset Voltage			3		mV
$\Delta V_{IO}/dt$	Offset Drift versus Temperature			- 10		$\mu V/^\circ C$
GV	Voltage Gain		80			dB
V_{5L}	Output Saturation Voltage to GND (Pin 4)	$I_5 = 1A$		1	1.7	V
V_{5H}	Output Saturation Voltage to Supply (Pin 6)	$I_5 = - 1A$		1.8	2.3	V
V_{D5-6}	Diode Forward Voltage between Pins 5-6	$I_5 = 1A$		1.3	2	V
V_{D3-2}	Diode Forward Voltage between Pins 3-2	$I_3 = 1A$		1.2	2	V
V_{3SL}	Saturation Voltage on Pin 3	$I_3 = 20mA$		0.4	1	V
V_{3SH}	Saturation Voltage to Pin 2 (2nd part of flyback)	$I_3 = - 1A$		2.1	2.8	V

9309-03.TBL

APPLICATION CIRCUITS

AC COUPLING



9309-03.EPS

APPLICATION CIRCUITS (continued)
DC COUPLING

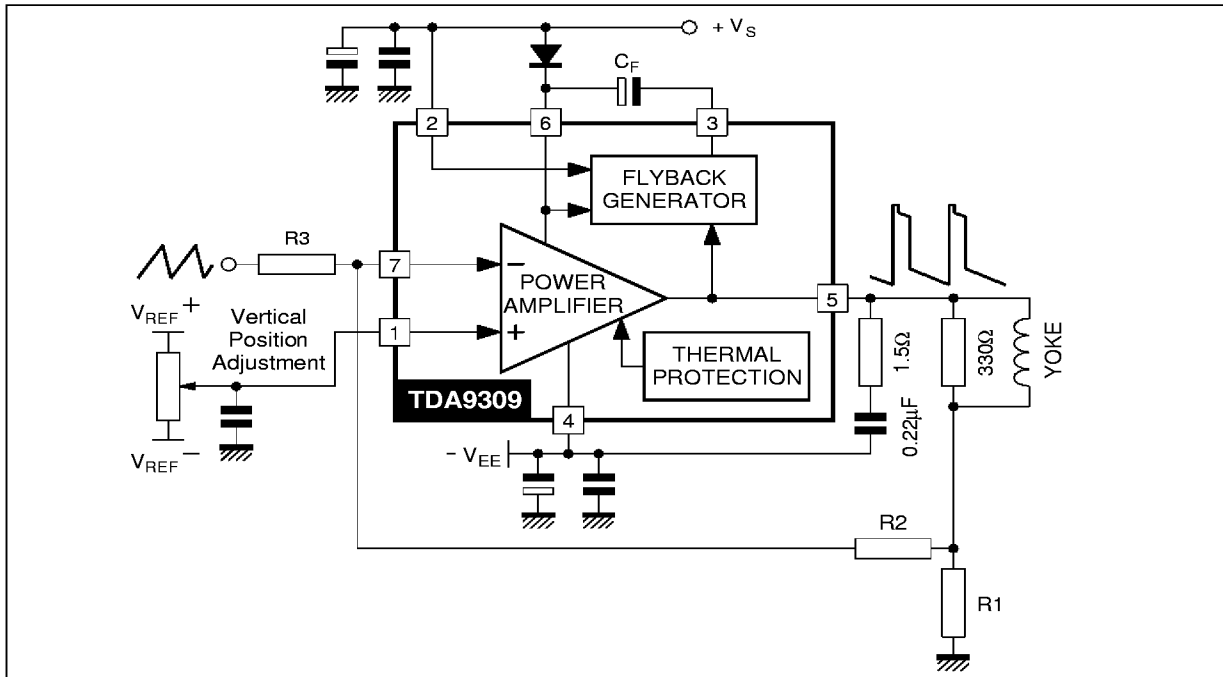
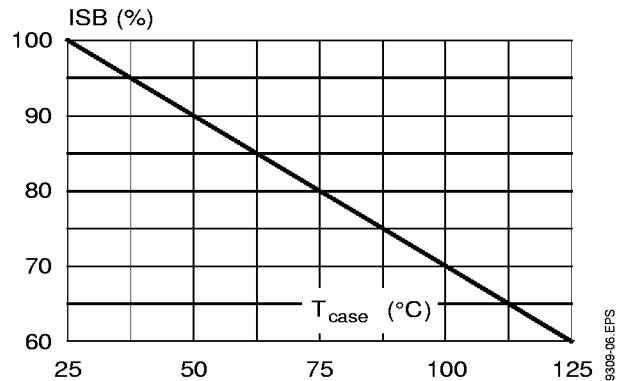
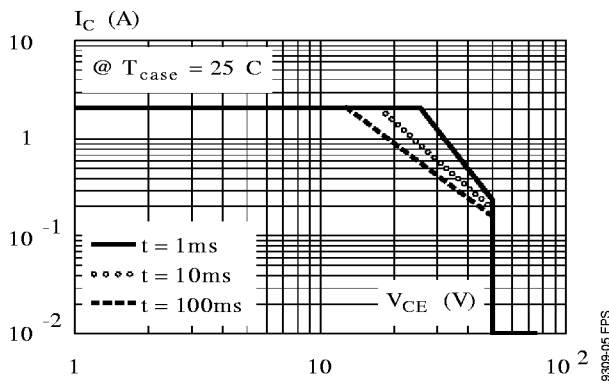


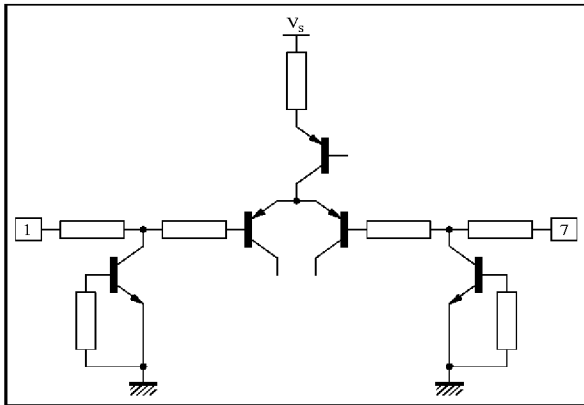
Figure 1 : Output Transistors SOA (for secondary breakdown)

Figure 2 : Secondary Breakdown Temperature Derating Curve (ISB = secondary breakdown current)



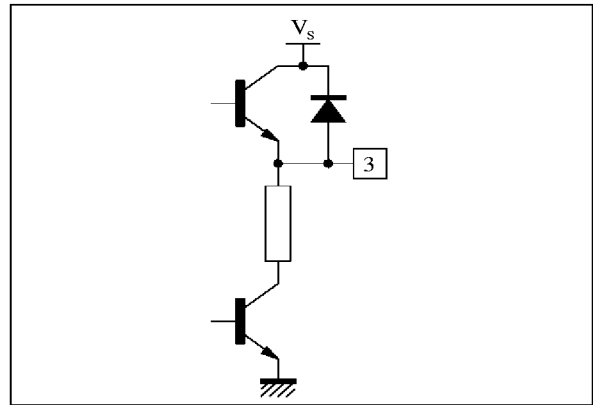
PIN CONFIGURATION

Figure 3 : Pins 1-7



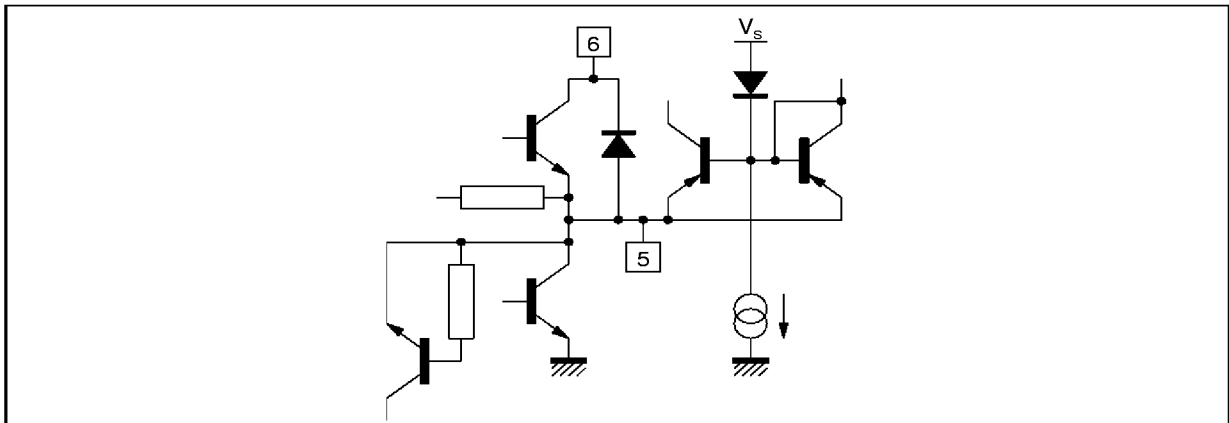
9309-07.EPS

Figure 4 : Pin 3



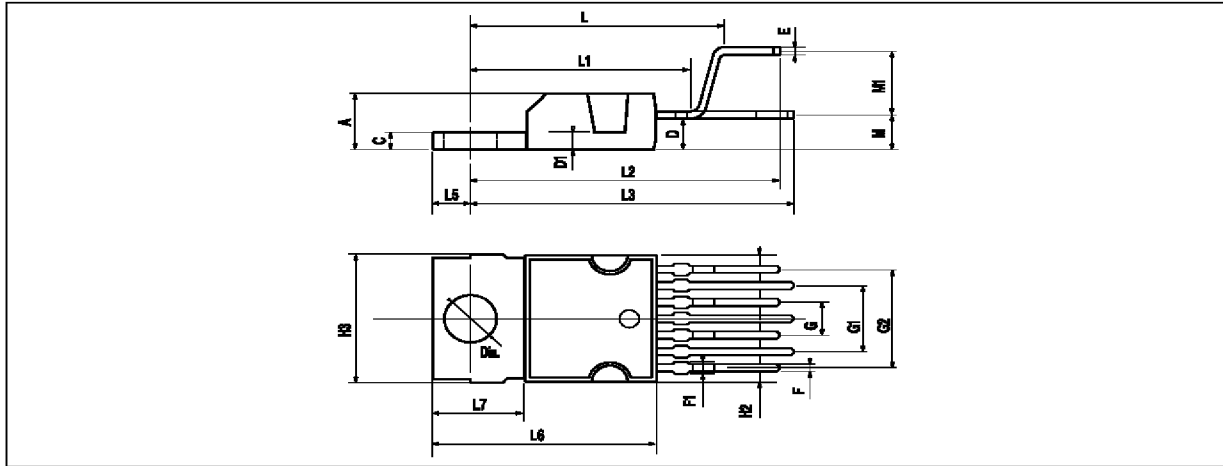
9309-08.EPS

Figure 5 : Pins 5-6



9309-09.EPS

PACKAGE MECHANICAL DATA : HEPTAWATT



PM-HEPTV.EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			4.8			0.189
C			1.37			0.054
D	2.4		2.8	0.094		0.110
D1	1.2		1.35	0.047		0.053
E	0.35		0.55	0.014		0.022
F	0.6		0.8	0.024		0.031
F1			0.9			0.035
G	2.41	2.54	2.67	0.095	0.100	0.105
G1	4.91	5.08	5.21	0.193	0.200	0.205
G2	7.49	7.62	7.8	0.295	0.300	0.307
H2			10.4			0.409
H3	10.05		10.4	0.396		0.409
L		16.97			0.668	
L1		14.92			0.587	
L2		21.54			0.848	
L3		22.62			0.891	
L5	2.6		3	0.102		0.118
L6	15.1		15.8	0.594		0.622
L7	6		6.6	0.236		0.260
M		2.8			0.110	
M1		5.08			0.200	
Dia.	3.65		3.85	0.144		0.152

HEPTV.TBL

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